

SPECIFICATION

Product: White Top-View SMD LED (3528)

Part No.: IWS-P351-UW-W

Date: 2008. 10. 27 Ver. 1.0

Proposed By	Checked By	Checked By	Checked By	Approval

Comment				



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IWS- P351-UW-W Version of 1.0 PAGE: 1 / 11
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Unit: mm

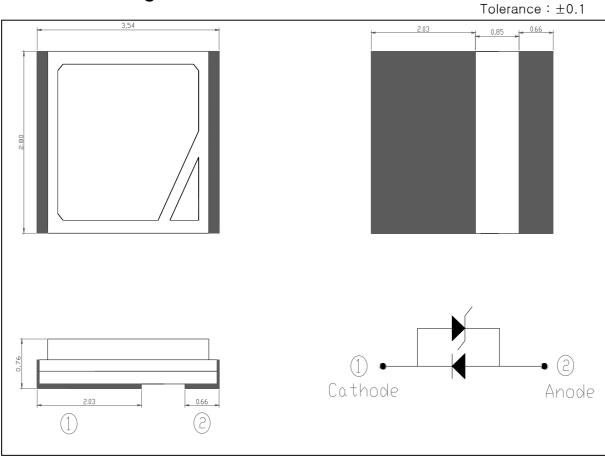
1. Features

- 1chip High-Luminosity Chip LED
- 3.5 mm x 2.8 mm x 0.76 mm (L x W x H) small size surface mount type
- · Wide Viewing angle
- · Long operating life

2. Applications

- Automotive: Backlight in dashboard and switch
- · Lighting device: Indicator, lighting
- · Camera flash, Hand Carrier Flash
- General use

3. Outline Drawing and Dimension



Note

- 1. All dimensions are in millimeters
- 2. All dimensions without tolerances are for reference only

IWS- P351-UW-W Version of 1.0 PAGE: 2/11	IWS- P351-UW-W	Version of 1.0	PAGE: 2 / 11
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4. Absolute Maximum Ratings (Ta = 25 $^{\circ}$ C)

Parameter	eter Symbol Value		Unit
Power Dissipation per chip	ipation per chip P _d		mW
Continuous Forward Current	vard Current I _F 100		mA
Peak Forward Current *1	I _{FP}	200	mA
Operating Temperature	T _{opr}	-30 ~ +85	
Storage Temperature	T _{stg}	-40 ~ +100	
Soldering Temperature	T _{sol}	260 (5sec)	

^{% 1} Duty ratio = 1/10, Pulse width = 10ms

5. Electrical & Optical Characteristics (Ta: 25℃)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit.
Forward Voltage	V_{F}	I _F = 100mA	2.0	3.3	3.6	V
Color Coordinates	CIE x CIE y	I _F = 100 mA	-	CIE x=0.43 CIE y=0.43	-	
Luminous Intensity*2	I _V	I _F = 100mA	4,000	-	8,000	mcd
Luminous Flux*3	Ф۷	I _F = 100mA	17	-	29	lm
View angle*4	2 0 _{1/2}	I _F = 100 mA	-	140	-	deg

^{**2} Luminous Intensity is tested by a tester calibrated by CAS 140B(CIE LED_B) and has an accuracy of 10%.

5.1 Luminous Intensity Rank (IF=100mA)

Rank	Luminous Intensity (mcd)
Q	4,000 ~ 5,000
R	5,000 ~ 6,000
S	6,000 ~ 7,000
Т	7,000 ~ 8,000

5.2 Luminous Flux Rank (IF=100mA)

Rank Luminous Flux (lm)	
4	17~22
5	22~29

IWS- P351-UW-W	Version of 1.0	PAGE: 3 / 11

^{*3} Luminous Flux is measured with an integrating sphere and has an accuracy of 10%.

^{*4} Viewing angle is the angle until 50% of brightness measured from the front part of LED.

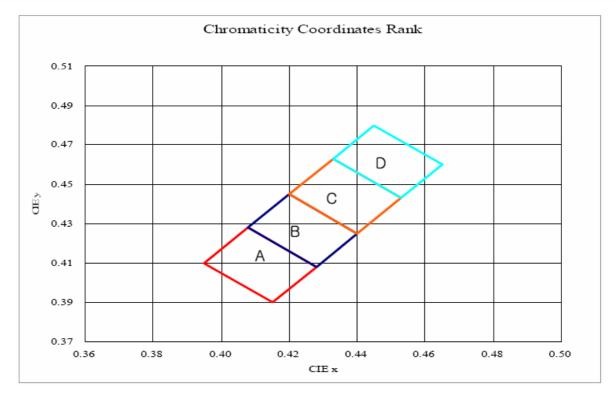


5.3 Forward Voltage Rank

Rank	Forward Voltage(V)	
А	3.0 ~ 3.2	
В	3.2 ~ 3.4	
С	3.4 ~ 3.6	

5.4 Color coordinates Rank (IF = 100 mA, Ta = 25 $^{\circ}$ C)

Ra	nk A	Rani	к В	Rank C		Ran	Rank D	
CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	
0.415	0.390	0.428	0.408	0.440	0.425	0.453	0.443	
0.395	0.410	0.408	0.428	0.420	0.445	0.433	0.463	
0.408	0.428	0.420	0.445	0.433	0.463	0.445	0.480	
0.428	0.408	0.440	0.425	0.453	0.443	0.465	0.460	



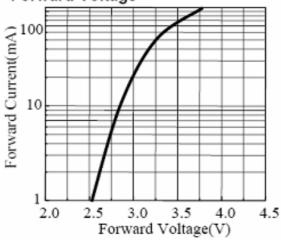
- * The CIE(1931) standard colorimetric system
- * Chromaticity coordinates Measured : 0.01sr(CIE. LED_B)
- * Measurement Uncertainty of the Color Coordinates : $\pm 0.01\,$

IWS- P351-UW-W Version of 1.0 PAGE: 4/1

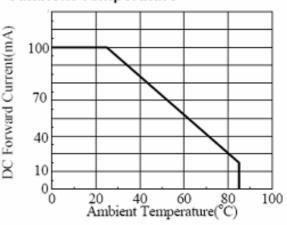


6. Typical Characteristic Curve

Forward Current vs. Forward Voltage



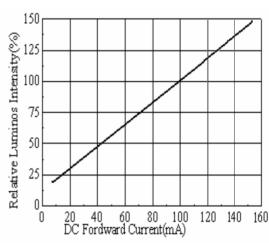
Forward Current vs. Ambient Temperature

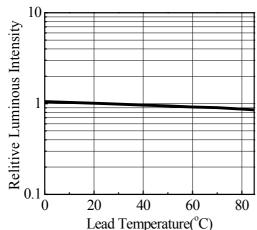


Relative Luminous Intensity vs. Ambient Temperature

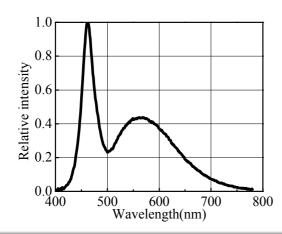


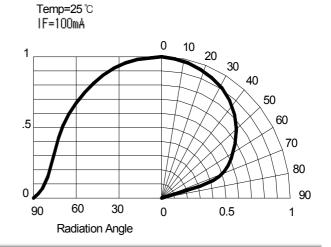






Relative Luminous Intensity vs. Wavelength **Radiation Diagram**



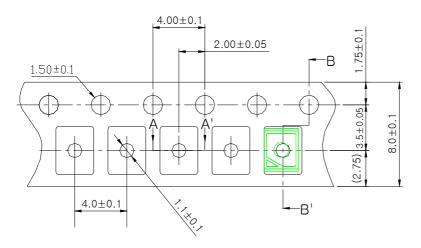


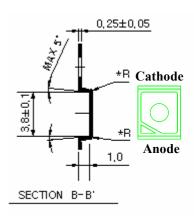
PAGE: 5/11 **IWS-P351-UW-W** Version of 1.0

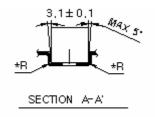


7. Dimension of Tape / Reel

7.1 Tape Dimension

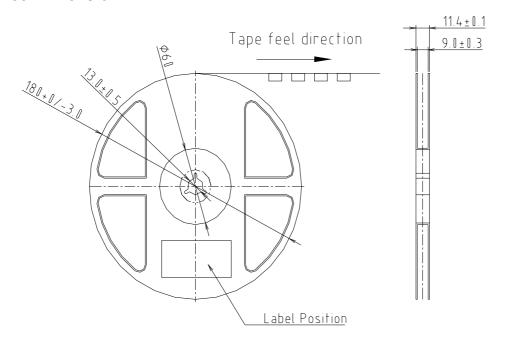






Tolerance ± 0.1 , Unit: mm

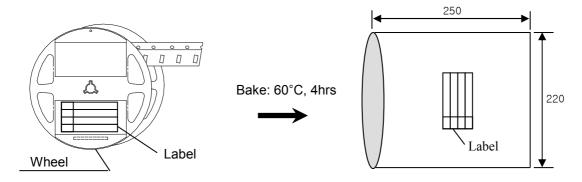
7.2 Reel Dimension





8. Packing Dimension

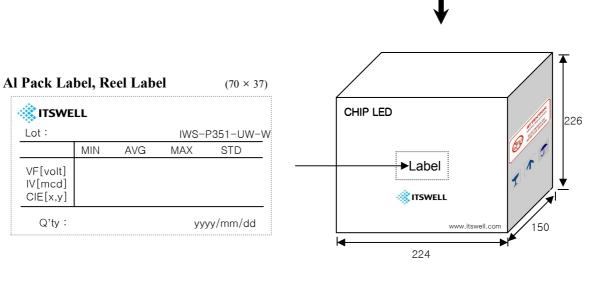
Unit:mm



Diameter: 180 mm Width: 12 mm

 $3528 \Rightarrow 3,000 \text{ pcs/Reel}$

Shield Bag(Polyester/Al/LDPE)
1 Reel/Bag (T = 0.1 mm) with Silica gel



Maximum 10 Bags / 1Inner Box 3528 ⇒ 30,000 pcs / 1 Inner Box

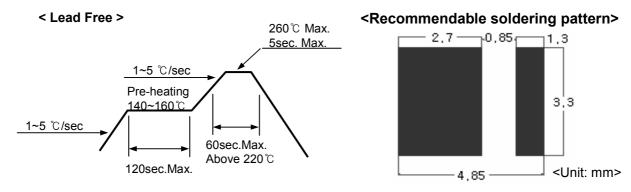
IWS- P351-UW-W Version of 1.0 PAGE: 7 / 11



9. Precaution in use

9.1 Soldering Conditions

- When soldering Power SMD, Heat may affect the electrical and optical characteristics of the LEDs.
- In soldering, do not stress the lead frame and the resin part under the high temperature.
- The silicone part should be protected from mechanical stress or vibration until the Power SMD return to room temperature after soldering.
- Preliminary heating to be at 160 °C max. for 120 Seconds max.
- For manual Soldering is Not more than 3 sec @MAX 350 °C, under soldering iron



9.2 Storage

■ Use with 7days after opening packing. Store in 10 to 30 °C Power SMD lead frames are plated silver. The silver surface may be affected by environment which contain corrosive gases and so on. Please avoid condition which may cause the Power SMD to corroded, tarnish or discolor.

9.3 Static Electricity

- Static electricity or surge voltage damages the Power SMD. It is recommended that a wrist band or an anti-electrostatic glove be used when handling the LEDs.
- A tip soldering iron is requested to be grounded. An ionizer should also be installed where risk of static.
- All devices, equipment and machinery must be properly grounded (via 1M\(\Omega\)). It is recommended that measures be taken against surge voltage to the equipment that mounts the Power SMD.

9.4 Cleaning

- Isopropyl Alcohol or Ethylene Alcohol is recommended in 5 minutes at room temperature.

 Don't use unspecified chemical may cause crack or haze on the surface of the epoxy resin.
- Before cleaning, a pre-test should be done to confirm whether any damage to the LED will occur.
- Freon solvents should not be used to clean the LEDs because of worldwide regulations.

9.5 Heat generation

- When the LEDs are illuminating, operating current should be decided after being considering the ambient maximum temperature.
- Please consider the heat generation of the LED when it is designed the PCB.
- The LED's must be mounted on MCPCB or heat sink or applied thermal pad.

IWS- P351-UW-W	Version of 1.0	PAGE: 8/11
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10. Reliability

10.1 Reliability Test Item

Test Items	Test Conditions	Notes
High Temperature Storage	100℃, 1,000hr.	0/25
Low Temperature Storage	-40℃, 1,000hr.	0/25
Temp. Humidity Storage	60℃, 90% RH, 1,000hr.	0/25
Steady State Operating life	25℃, 100mA/chip , 1,000hr.	0/25
High Temperature Operating Life	85℃, 25mA, 1,000hr	0/25
Low Temperature Operating Life	-30℃, 100mA, 1,000hr.	0/25
Steady State Operating life Of High Humidity Heat	60℃, 90% RH, 75mA, 1,000hr.	0/25
Temperature Cycle	-40 °C (30min)→100 °C (30min.), 100 cycle	0/25
ESD	HBM, 100 pF, 1.5 kohm, 3 times	0/25

10.2 Criteria for Judging the Damage

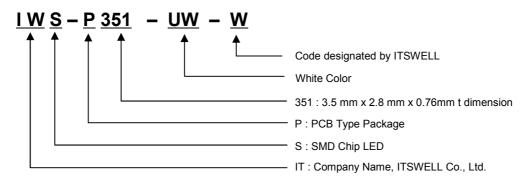
Items	Items Test Conditions Criteria for judgment	
Luminous Intensity (IV)	I _F = 100mA	> 70% of S
Forward Voltage (VF)	I _F = 100mA	Less than 110% of U

^{*} U means the upper limit of specified characteristics, S means initial value.

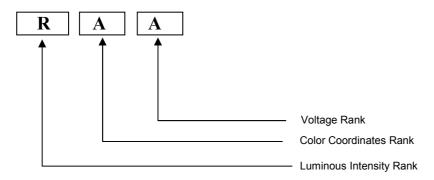
IWS- P351-UW-W	Version of 1.0	PAGE: 9/11
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11. Part Name Description



12. Rank Description



IWS- P351-UW-W Version of 1.0 PAGE: 10 / 11



■ Spec. Review History

Review Ver.	Date	Correction List	Etc.
Ver 1.0	2008.10.27	Establish	

IWS- P351-UW-W	Version of 1.0	PAGE: 11 / 11
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